



*Ain Shams University
Faculty of Education
Physics Department*

**Effect of γ -radiation on the electrical
characterization of two dimensional
island metal films (2D-IMF)**

THESIS

*Submitted for the Degree of doctor of Philosophy for
the Teacher Preparation in Science (Physics)*

By

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To

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بِسْمِ اللَّهِ الرَّحْمَنِ الرَّحِيمِ

{ وَمَا أَوْتَيْتُمْ مِنَ الْعِلْمِ إِلَّا قَلِيلًا }

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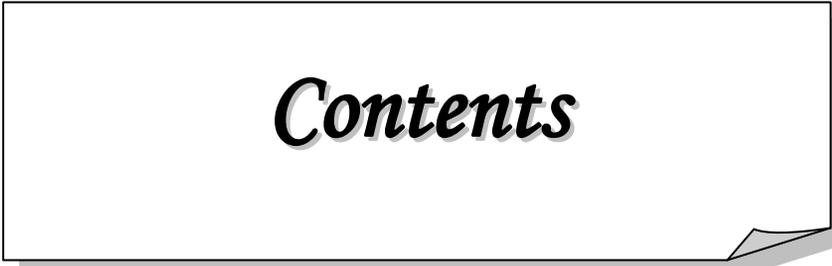
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